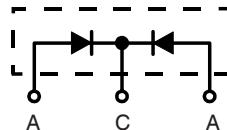


# Common Cathode Fast Recovery Epitaxial Diode (FRED)

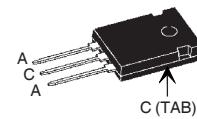
## DSEK 60

**I<sub>FAVM</sub> = 2x 34 A**  
**V<sub>RRM</sub> = 200 V**  
**t<sub>rr</sub> = 35 ns**

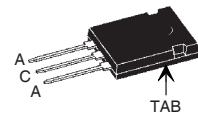
V <sub>RSM</sub> V	V <sub>RRM</sub> V	Type
200	200	DSEK 60-02A
200	200	DSEK 60-02AR



TO-247 AD  
Version A



ISOPLUS 247™  
Version AR



A = Anode, C = Cathode

Symbol	Test Conditions	Maximum Ratings per leg	
I <sub>FRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	50	A
I <sub>FAVM</sub> *	T <sub>C</sub> = 115°C; rectangular, d = 0.5	34	A
I <sub>FRM</sub>	t <sub>p</sub> < 10 µs; rep. rating, pulse width limited by T <sub>VJM</sub>	375	A
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine	325	A
	t = 8.3 ms (60 Hz), sine	350	A
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine	290	A
	t = 8.3 ms (60 Hz), sine	310	A
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C t = 10 ms (50 Hz), sine	530	A <sup>2</sup> s
	t = 8.3 ms (60 Hz), sine	510	A <sup>2</sup> s
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine	420	A <sup>2</sup> s
	t = 8.3 ms (60 Hz), sine	400	A <sup>2</sup> s
T <sub>VJ</sub>		-40...+150	°C
T <sub>VJM</sub>		150	°C
T <sub>stg</sub>		-40...+150	°C
P <sub>tot</sub>	T <sub>C</sub> = 25°C	125	W
M <sub>d</sub> *	Mounting torque with screw M3	0.45-0.55/4-5	Nm/lb.in.
	Mounting torque with screw M3.5	0.45-0.55/4-5	Nm/lb.in.
V <sub>ISOL</sub> **	50/60 Hz, RMS, t = 1 minute, leads-to-tab	2500	V~
<b>Weight</b>		6	g

\* Version A only; \*\* Version AR only

Symbol	Test Conditions	Characteristic Values per leg	
		typ.	max.
I <sub>R</sub>	T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 125°C	V <sub>R</sub> = V <sub>RRM</sub> V <sub>R</sub> = 0.8 • V <sub>RRM</sub> V <sub>R</sub> = 0.8 • V <sub>RRM</sub>	200 50µA 5 mA
V <sub>F</sub>	I <sub>F</sub> = 30 A; T <sub>VJ</sub> = 150°C T <sub>VJ</sub> = 25°C		0.85 1.10
V <sub>TO</sub>	For power-loss calculations only		0.72
r <sub>T</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>		4.2
mΩ			
R <sub>thJC</sub>			1 K/W
R <sub>thCH</sub>		0.5	K/W
t <sub>rr</sub>	I <sub>F</sub> = 1 A, -di/dt = 100 A/µs, V <sub>R</sub> = 30 V, T <sub>VJ</sub> = 25°C	35	50ns
I <sub>RM</sub>	V <sub>R</sub> = 100 V; I <sub>F</sub> = 30 A; -di <sub>F</sub> /dt = 100 A/µs L ≤ 0.05 µH, T <sub>VJ</sub> = 25°C	4	5 A

\* I<sub>FAVM</sub> rating includes reverse blocking losses at T<sub>VJM</sub>, V<sub>R</sub> = 0.8 V<sub>RRM</sub>, duty cycle d = 0.5  
Data according to IEC 60747 refer to a single diode unless otherwise stated.

IXYS reserves the right to change limits, test conditions and dimensions

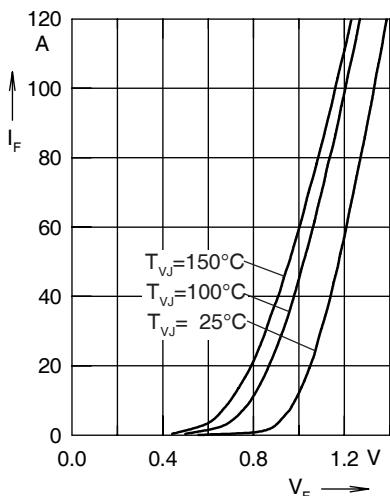
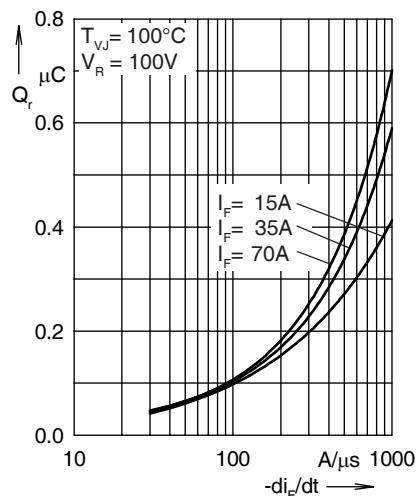
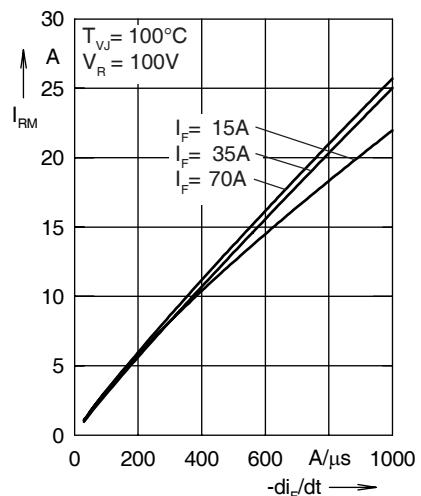
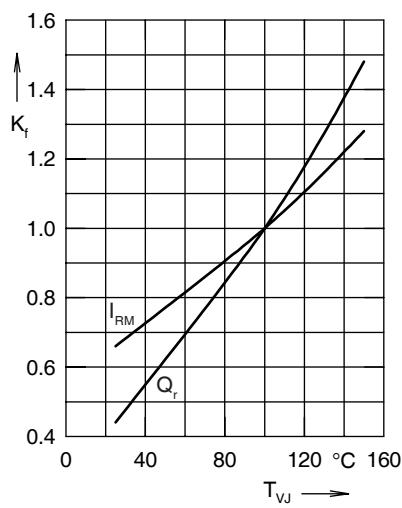
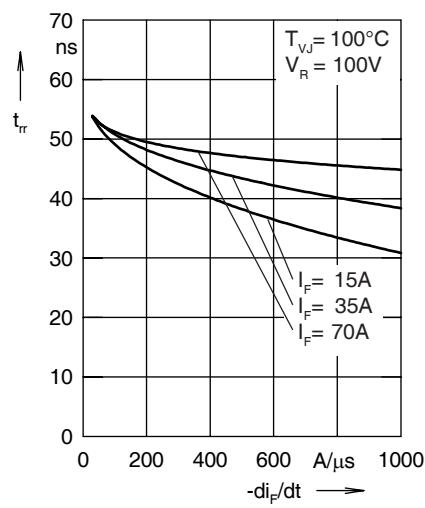
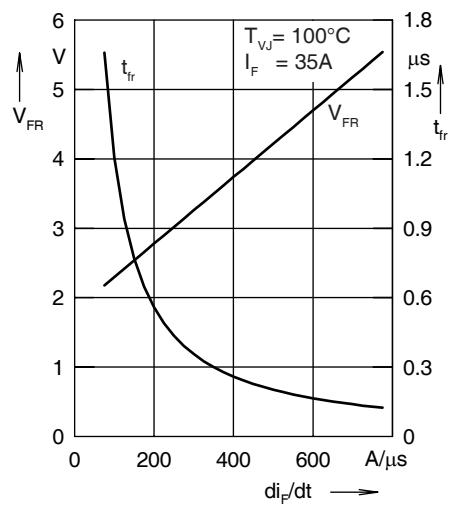
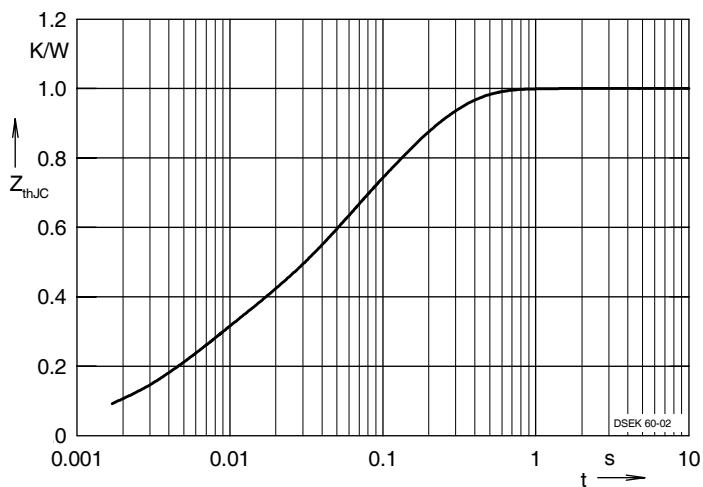
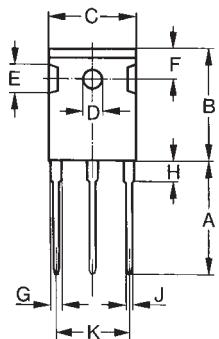
Fig. 1 Forward current  $I_F$  versus  $V_F$ Fig. 2 Typ. reverse recovery charge  $Q_r$  versus  $-di_F/dt$ Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $-di_F/dt$ Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$ Fig. 5 Typ. recovery time  $t_{rr}$  versus  $-di_F/dt$ Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$ 

Fig. 7 Transient thermal impedance junction to case

## Dimensions



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	2.2	2.54	0.087	0.102